

40V N-Channel Enhancement Mode MOSFET

Voltage

Current 120 A

Features

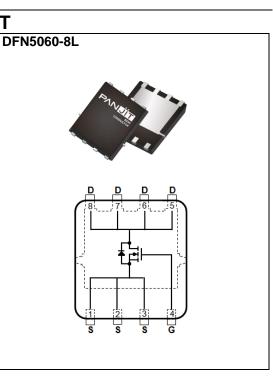
• $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A<3.6m\Omega$

40 V

- Rds(on), Vgs@7V, Id@20A<4.6m Ω
- Excellent FOM
- Standard Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40	V	
Gate-Source Voltage		V _{GS}	±20		
Continuous Drain Current ^(Note 3)	120				
	Tc=100°C	ID	85	А	
Pulsed Drain Current ^(Note 1)	T _C =25°C	I _{DM}	480		
Power Dissipation	T _C =25°C		94	14/	
	Tc=100°C	Po	47	W	
Continuous Drain Current ^(Note 4)	T _A =25°C		22.7	٨	
	T _A =70°C	I _D	19	— A	
Power Dissipation	T _A =25°C	Do	3.3	w	
	T _A =70°C	Po	2.3	vv	
Single Pulse Avalanche Energy ^(Note 5)		Eas	210	mJ	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~175	°C	
Thermal Resistance ^(Note 4)	Junction to Case	R _{θJC}	1.6		
	Junction to Ambient	R _{θJA}	45		



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	Ň
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =50uA	2	2.8	3.5	V
Ducia Course On State Decisteres		V _{GS} =10V, I _D =20A	-	2.9	3.6	mΩ
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =7V, I _D =20A	-	3.5	4.6	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =40V, V_{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic ^(Note 6)	-	-		•	•	-
Total Gate Charge	Qg	V _{DS} =32V, I _D =20A, V _{GS} =10V	-	34	-	nC
Gate-Source Charge	Qgs		-	11	-	
Gate-Drain Charge	Q_{gd}		-	4	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1MHz	-	2544	-	pF
Output Capacitance	Coss		-	633	-	
Reverse Transfer Capacitance	Crss		-	49	-	
Gate resistance	Rg	f=1MHz	-	1	-	Ω
Turn-On Delay Time	td _(on)	V _{DS} =32V, I _D =20A, V _{GS} =10V, R _G =3Ω (Note 2)	-	30	-	ns
Turn-On Rise Time	tr		-	87	-	
Turn-Off Delay Time	td(off)		-	49	-	
Turn-Off Fall Time	tf		-	28	-	
Drain-Source Diode	·					
Diode Forward Current	Is	Tc=25°C	-	-	120	А
Pulsed Diode Forward Current	I _{SM}		-	-	480	
Diode Forward Voltage	V _{SD}	Is=20A, V _{GS} =0V	-	0.82	1.3	V
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =20A	-	35	-	ns
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	26	-	nC

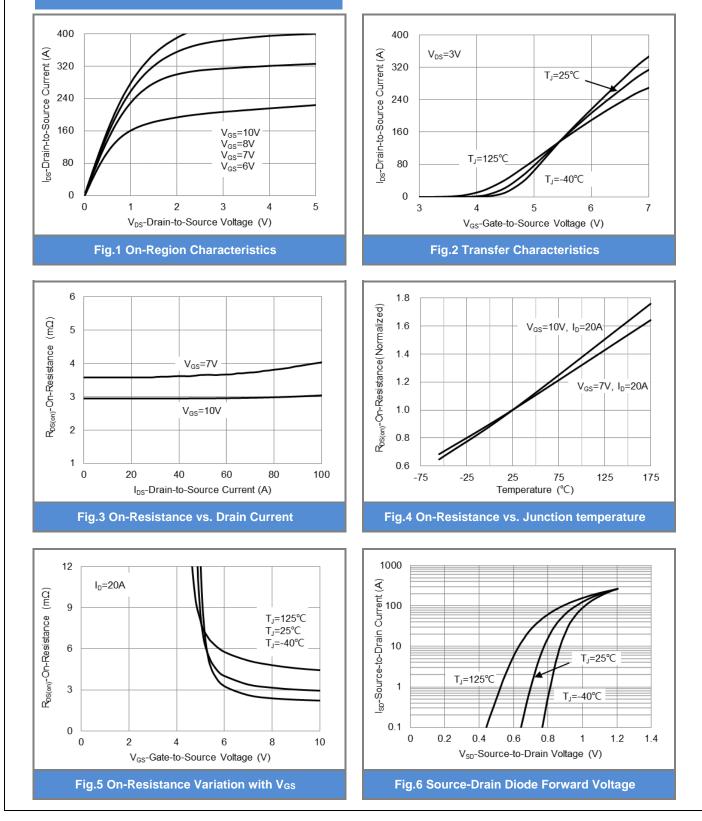
NOTES :

- 1. Pulse width100us, Duty cycle<2%.</td>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}$ =1.6°C/W, Pakage limited 100A.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS}=29A, V_{DD}=30V, V_{GS}=10V, Starting T_J=25 ^{\circ}C.
- 6. Guaranteed by design, not subject to production testing.

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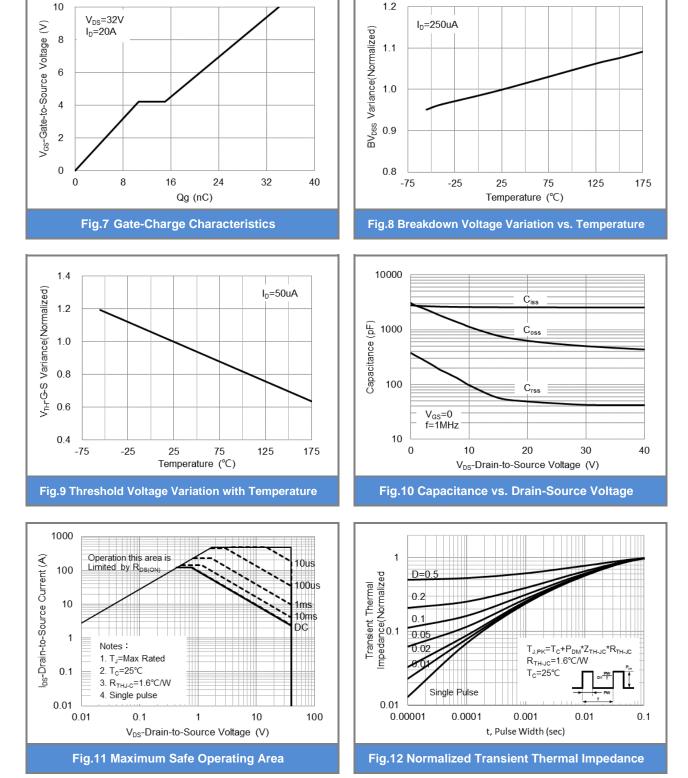
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TYPICAL CHARACTERISTIC CURVES

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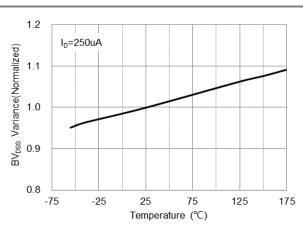
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TYPICAL CHARACTERISTIC CURVES

SEM CONDUCTOR PJQ5544V-AU





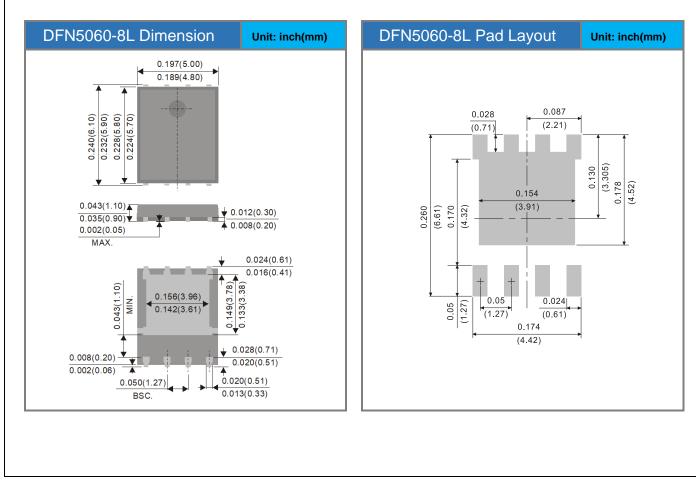




Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ5544V-AU_R2_002A1	DFN5060-8L	3K pcs / 13" reel	Q5544V	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout



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